### INTEGRATED CIRCUITS

# DATA SHEET

# 74LVT16501A

3.3V LVT 18-bit universal bus transceiver (3-State)

Product specification
Supersedes data of 1997 Jun 12
IC23 Data Handbook





# 3.3V 18-bit universal bus transceiver (3-State)

### 74LVT16501A

#### **FEATURES**

- 18-bit bidirectional bus interface
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up reset
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Positive edge triggered clock inputs
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

#### **DESCRIPTION**

The 74LVT16501A is a high-performance BiCMOS product designed for  $V_{CC}$  operation at 3.3V.

This device is an 18-bit universal transceiver featuring non-inverting 3-State bus compatible outputs in both send and receive directions. Data flow in each direction is controlled by output enable (OEAB and OEBA), latch enable (LEAB and LEBA), and clock (CPAB and CPBA) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is High. When LEAB is Low, the A data is latched if CPAB is held at a High or Low logic level. If LEAB is Low, the A-bus data is stored in the latch/flip-flop on the Low-to-High transition of CPAB. When OEAB is High, the outputs are active. When OEAB is Low, the outputs are in the high-impedance state.

Data flow for B-to-A is similar to that of A-to-B but uses  $\overline{\text{OEBA}}$ , LEBA and CPBA. The output enables are complimentary (OEAB is active High, and  $\overline{\text{OEBA}}$  is active Low).

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25°C	TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An to Bn or Bn to An	$C_L = 50pF;$ $V_{CC} = 3.3V$	1.9	ns
C <sub>IN</sub>	Input capacitance (Control pins)	$V_I = 0V \text{ or } 3.0V$	3	pF
C <sub>I/O</sub>	I/O pin capacitance	Outputs disabled; V <sub>I/O</sub> = 0V or 3.0V	9	pF
I <sub>CCZ</sub>	Total supply current	Outputs disabled; V <sub>CC</sub> = 3.6V	70	μΑ

#### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
56-Pin Plastic SSOP Type III	-40°C to +85°C	74LVT16501A DL	VT16501A DL	SOT371-1
56-Pin Plastic TSSOP Type II	-40°C to +85°C	74LVT16501A DGG	VT16501A DGG	SOT364-1

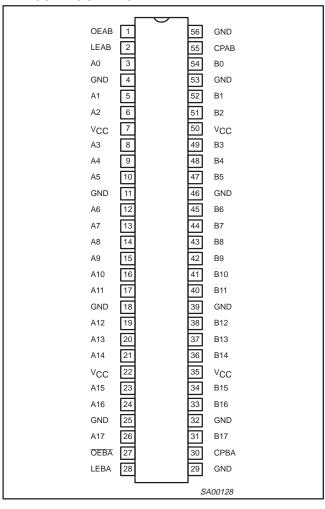
#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	OEAB	A-to-B Output enable input
27	ŌEBĀ	B-to-A Output enable input (active low)
2, 28	LEAB/LEBA	A-to-B/B-to-A Latch enable input
55,30	CPAB/CPBA	A-to-B/B-to-A Clock input (active rising edge)
3, 5, 6, 8, 9, 10, 12, 13, 14, 15, 16, 17, 19, 20, 21, 23, 24, 26	A0-A17	Data inputs/outputs (A side)
54, 52, 51, 49, 48, 47, 45, 44, 43, 42, 41, 40, 38, 37, 36, 34, 33, 31	B0-B17	Data inputs/outputs (B side)
4, 11, 18, 25, 32, 39, 46, 53	GND	Ground (0V)
7, 22, 35, 50	V <sub>CC</sub>	Positive supply voltage

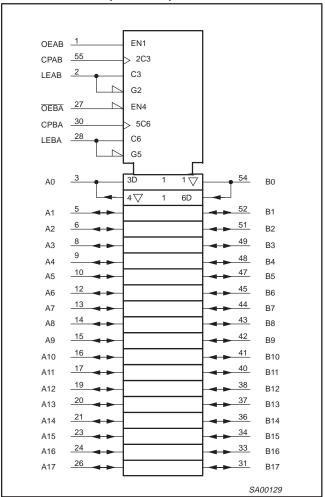
# 3.3V 18-bit universal bus transceiver (3-State)

### 74LVT16501A

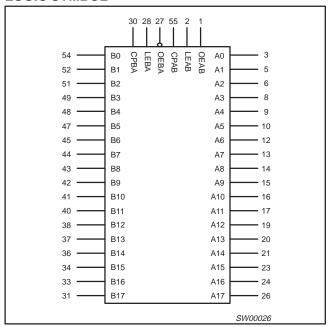
#### **PIN CONFIGURATION**



### LOGIC SYMBOL (IEEE/IEC)



#### **LOGIC SYMBOL**



# 3.3V 18-bit universal bus transceiver (3-State)

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#### **FUNCTION TABLE**

	INP	UTS		INTERNAL	OUTPUTS	OPERATING MODE
OEAB	LEAB	CPAB	An	REGISTER	Bn	OPERATING MODE
L	Н	Х	Х	Х	Z	Disabled
L	$\downarrow$	Х	h	Н	Z	Dischlad Latah data
L	$\downarrow$	Х	I	L	Z	Disabled, Latch data
L	L	H or L	Х	NC	Z	Disabled, Hold data
L	L	<b>↑</b>	h	Н	Z	Disabled, Clock data
L	L	<b>↑</b>	Ι	L	Z	Disabled, Clock data
Н	Н	Х	Н	Н	Н	Transparent
Н	Н	Х	L	L	L	Transparent
Н	$\downarrow$	Х	h	Н	Н	Latab data & diaplay
Н	$\downarrow$	Х	Ι	L	L	Latch data & display
Н	L	<b>↑</b>	h	Н	Н	Clock data & diaplay
Н	L	<b>↑</b>	I	L	L	Clock data & display
Н	L	H or L	Х	Н	Н	Hold data & display
Н	L	H or L	Х	L	L	Hold data & display

NOTE: A-to-B data flow is shown; B-to-A flow is similar but uses OEBA, LEBA, and CPBA.

H = High voltage level
h = High voltage level one set-up time prior to the Enable or Clock transition

L = Low voltage level

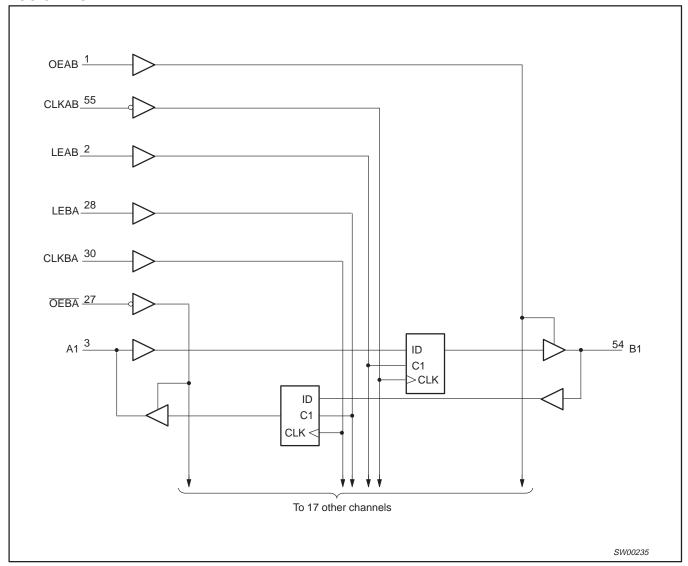
I = Low voltage level one set-up time prior to the Enable or Clock transition NC= No Change

X = Don't care
Z = High Impedence "off" state
↓ = High-to-Low Enable or Clock transition

# 3.3V 18-bit universal bus transceiver (3-State)

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### **LOGIC DIAGRAM**



# 3.3V 18-bit universal bus transceiver (3-State)

74LVT16501A

### ABSOLUTE MAXIMUM RATINGS 1, 2

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < 0	-50	mA
VI	DC input voltage <sup>3</sup>		-0.5 to +7.0	V
lok	DC output diode current	V <sub>O</sub> < 0	-50	mA
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	Output in Off or High state	-0.5 to +7.0	V
	DC output ourrent	Output in Low state	128	A
Гоит	DC output current	Output in High state	-64	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C

#### NOTES:

#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	LIM	UNIT		
STWIBUL	PARAMETER	MIN	MAX	UNII	
V <sub>CC</sub>	DC supply voltage	2.7	3.6	V	
VI	Input voltage	0	5.5	V	
V <sub>IH</sub>	High-level input voltage	2.0		V	
$V_{IL}$	Input voltage		0.8	V	
I <sub>OH</sub>	High-level output current		-32	mA	
	Low-level output current		32		
l <sub>OL</sub>	Low-level output current; current duty cycle ≤ 50%; f ≥ 1kHz	cycle ≤ 50%; f ≥ 1kHz		mA	
Δt/Δν	Input transition rise or fall rate; Outputs enabled		10	ns/V	
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C	

<sup>1.</sup> Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

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#### DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS		Temp =	-40°C to	+85°C	UNIT
				MIN	TYP <sup>1</sup>	MAX	
V <sub>IK</sub>	Input clamp voltage	V <sub>CC</sub> = 2.7V; I <sub>IK</sub> = -18mA			-0.85	-1.2	V
		$V_{CC} = 2.7 \text{ to } 3.6 \text{V}; I_{OH} = -100 \mu\text{A}$		V <sub>CC</sub> -0.2	V <sub>CC</sub>		
$V_{OH}$	High-level output voltage	V <sub>CC</sub> = 2.7V; I <sub>OH</sub> = -8mA		2.4	2.55		V
		$V_{CC} = 3.0V; I_{OH} = -32mA$		2.0	2.3		1
		$V_{CC} = 2.7V; I_{OL} = 100\mu A$			0.07	0.2	
		V <sub>CC</sub> = 2.7V; I <sub>OL</sub> = 24mA			0.3	0.5	1
$V_{OL}$	Low-level output voltage	V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 16mA			0.25	0.4	V
		V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 32mA			0.3	0.5	1
		V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 64mA			0.36	0.55	
V <sub>RST</sub>	Power-up output low voltage <sup>5</sup>	$V_{CC} = 3.6V$ ; $I_O = 1$ mA; $V_I = GND$ or $V_{CC}$			0.1	0.55	٧
		$V_{CC} = 3.6V$ ; $V_I = V_{CC}$ or GND			0.1	±1	
		V <sub>CC</sub> = 0 or 3.6V; V <sub>I</sub> = 5.5V	Control pins		0.1	10	1
II	Input leakage current	V <sub>CC</sub> = 3.6V; V <sub>I</sub> = 5.5V			1.0	20	μΑ
		V <sub>CC</sub> = 3.6V; V <sub>I</sub> = V <sub>CC</sub>	I/O Data pins <sup>4</sup>		0.1	10	
		V <sub>CC</sub> = 3.6V; V <sub>I</sub> = 0			0.1	-5	
I <sub>OFF</sub>	Output off current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5V$			1.0	±100	μА
		V <sub>CC</sub> = 3V; V <sub>I</sub> = 0.8V		75	130		
$I_{HOLD}$	Bus Hold current  A or B outputs <sup>7</sup>	V <sub>CC</sub> = 3V; V <sub>I</sub> = 2.0V		-75	-130		μΑ
	A or B outputs	V <sub>CC</sub> = 0V to 3.6V; V <sub>CC</sub> = 3.6V		±500			
I <sub>EX</sub>	Current into an output in the High state when $V_O > V_{CC}$	V <sub>O</sub> = 5.5V; V <sub>CC</sub> = 3.0V			50	125	μА
I <sub>PU/PD</sub>	Power up/down 3-State output current <sup>3</sup>	$V_{CC} \le 1.2V$ ; $V_O = 0.5V$ to $V_{CC}$ ; $V_I = GNE$ OE/OE = Don't care		40	±100	μА	
I <sub>CCH</sub>		$V_{CC} = 3.6V$ ; Outputs High, $V_I = GND$ or $V_{CC}$ , $I_O = 0$			0.07	0.12	
I <sub>CCL</sub>	Quiescent supply current	$V_{CC} = 3.6V$ ; Outputs Low, $V_I = GND$ or $V_{CC}$ , $I_O = 0$			4	5	mA
I <sub>CCZ</sub>	1	V <sub>CC</sub> = 3.6V; Outputs Disabled; V <sub>I</sub> = GND	or $V_{CC}$ , $I_{O} = 0^{6}$		0.07	0.12	1
Δl <sub>CC</sub>	Additional supply current per input pin <sup>2</sup>	$V_{CC}$ = 3V to 3.6V; One input at $V_{CC}$ -0.6\ Other inputs at $V_{CC}$ or GND	/,		0.1	0.2	mA

- All typical values are at V<sub>CC</sub> = 3.3V and T<sub>amb</sub> = 25°C.
   This is the increase in supply current for each input at the specified voltage level other than V<sub>CC</sub> or GND
   This parameter is valid for any V<sub>CC</sub> between 0V and 1.2V with a transition time of up to 10msec. From V<sub>CC</sub> = 1.2V to V<sub>CC</sub> = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T<sub>amb</sub> = 25°C only.
   Unused pins at V<sub>CC</sub> or GND.
- For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.
   I<sub>CCZ</sub> is measured with outputs pulled to V<sub>CC</sub> or GND.
   This is the bus hold overdrive current required to force the input to the opposite logic state.

# 3.3V 18-bit universal bus transceiver (3-State)

# 74LVT16501A

#### **AC CHARACTERISTICS**

GND = 0V;  $t_R$  =  $t_F$  = 2.5ns;  $C_L$  = 50pF;  $R_L$  = 500 $\Omega$ ;  $T_{amb}$  = -40°C to +85°C.

SYMBOL	PARAMETER	WAVEFORM	V <sub>C</sub>	<sub>C</sub> = 3.3V ±0	.3V	V <sub>CC</sub> = 2.7V	UNIT
			MIN	TYP <sup>1</sup>	MAX	MAX	
f <sub>MAX</sub>	Maximum clock frequency	1	150				MHz
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An to Bn or Bn to An	2	0.5 0.5	1.9 1.9	4.2 4.2	5.4 5.4	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay CPAB to Bn or CPBA to An	1	1.0 1.0	3.2 3.2	5.4 5.4	6.4 6.4	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay LEAB to Bn or LEBA to An	3	1.0 1.0	2.4 2.9	5.4 5.4	6.4 6.4	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time to High and Low level	5 6	1.0 1.0	2.4 2.2	3.9 3.9	4.6 5.2	ns
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time from High and Low Level	5 6	1.0 1.0	2.8 3.2	5.2 5.2	5.6 5.6	ns

#### NOTE

#### **AC SETUP REQUIREMENTS**

GND = 0V;  $t_R$  =  $t_F$  = 2.5ns;  $C_L$  = 50pF,  $R_L$  = 500 $\Omega$ ;  $T_{amb}$  = -40°C to +85°C.

SYMBOL	PARAMETER	WAVEFORM	V <sub>CC</sub> = 3.3	3V ±0.3V	V <sub>CC</sub> = 2.7V	UNIT
			MIN	TYP	MIN	
ts(H) ts(L)	Setup time, High or Low An to CPAB or Bn to CPBA	4	1.8 1.8	1.0 0.7	1.5 1.5	ns
th(H) th(L)	Hold time, High or Low An to CPAB or Bn to CPBA	4	0 0	0 0	0 0	ns
ts(H) ts(L)	Setup time, High or Low An to LEAB or Bn to CPBA	4	1.8 1.8	1.1 1.8	1.5 1.5	ns
th(H) th(L)	Hold time, High or Low An to LEAB or Bn to LEBA	4	0 0	0 0	0 0	ns
tw(H) tw(L)	Pulse width, High or Low CPAB or CPBA	1	1.2 1.2	0.8 0.8	1.5 1.5	ns
tw(H)	LEAB or LEBA pulse width, High	3	1.2	0.8	1.5	ns

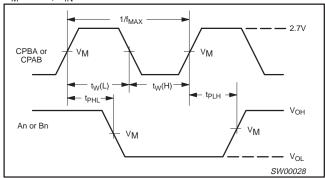
<sup>1.</sup> All typical values are at  $V_{CC}$  = 3.3V and  $T_{amb}$  = 25°C.

# 3.3V 18-bit universal bus transceiver (3-State)

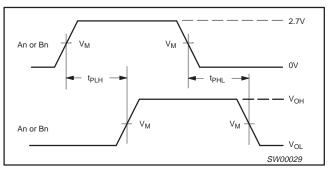
### 74LVT16501A

#### **AC WAVEFORMS**

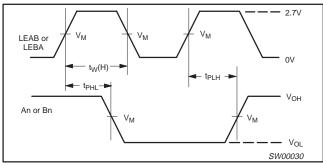
 $V_{M} = 1.5V$ ,  $V_{IN} = GND$  to 2.7V



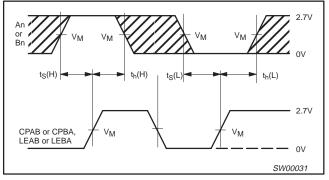
Waveform 1. Propagation Delay, Clock Input to Output, Clock Pulse Width, and Maximum Clock Frequency



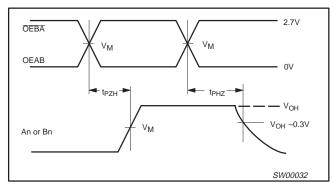
Waveform 2. Propagation Delay, Transparent Mode



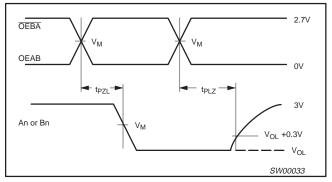
Waveform 3. Propagation Delay, Enable to Output, and Enable Pulse Width



Waveform 4. Data Setup and Hold Times



Waveform 5. 3-State Output Enable Time to High Level and Output Disable Time from High Level

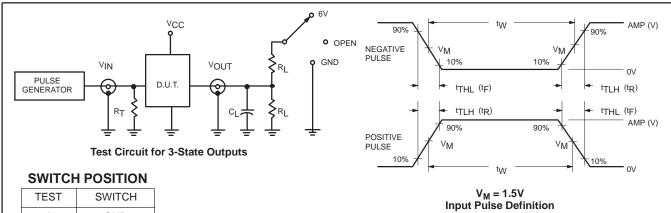


Waveform 6. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

# 3.3V 18-bit universal bus transceiver (3-State)

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#### **TEST CIRCUIT AND WAVEFORMS**



TEST	SWITCH
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND
t <sub>PLZ</sub> /t <sub>PZL</sub>	6V
t <sub>PLH</sub> /t <sub>PHL</sub>	open

#### **DEFINITIONS**

R<sub>L</sub> = Load resistor; see AC CHARACTERISTICS for value.

 $C_L = Load$  capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

FAMILY	INPUT PULSE REQUIREMENTS						
FAMILY	Amplitude	Rep. Rate	t <sub>W</sub>	t <sub>R</sub>	t <sub>F</sub>		
74LVT16	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns		

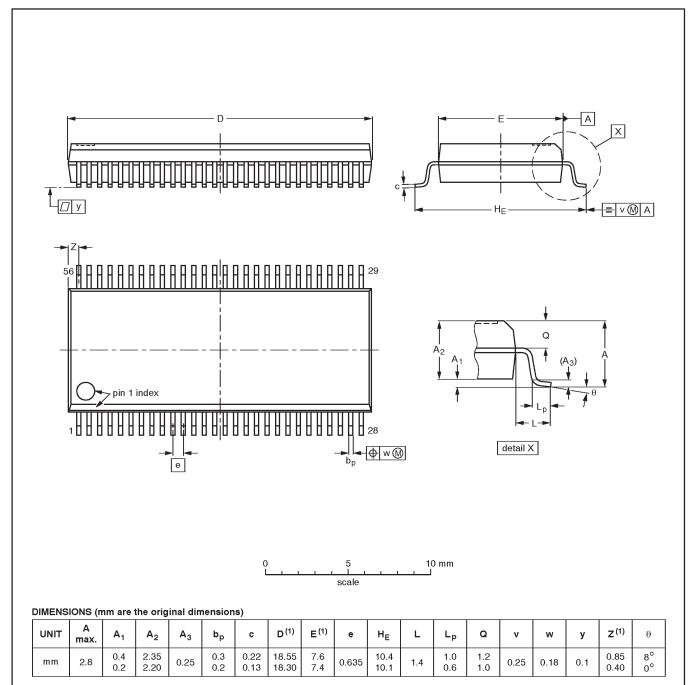
SW00003

# 3.3V LVT18-bit universal bus transceiver (3-State)

### 74LVT16501A

### SSOP56: plastic shrink small outline package; 56 leads; body width 7.5 mm

SOT371-1



#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	REFERENCES			ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT371-1		MO-118AB				<del>93-11-02</del> 95-02-04

plastic thin shrink small outline package; 56 leads; body width 6.1mm

# 3.3V LVT18-bit universal bus transceiver (3-State)

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0.8

0.4

detail X

0 to 8°

MSA400

SOT364-1

14.4 13.9 0.2 0.1 0.1 56 10.1 56 10.1 56 10.1 10.5 10.

0.27 0.08 (M)

0.5

1998 Feb 19 12

pin 1 index

Dimensions in mm.

3.3V LVT18-bit universal bus transceiver (3-State)

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**NOTES** 

### 3.3V LVT18-bit universal bus transceiver (3-State)

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#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

<sup>[1]</sup> Please consult the most recently issued datasheet before initiating or completing a design.

#### **Definitions**

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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